P3CD08065B

650V/8A SiC Power Schottky Barrier Diode Product

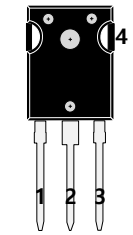
PowerCubeSemi, Inc.
Potential · Convergence · Smart

Features

- Positive temperature coefficient for easy parallel use
- Switching characteristics that are not affected by temperature
- Maximum operating temperature 175 ° C
- Zero reverse recovery current
- Zero forward recovery voltage

Key Characteristics		
V_{RRM}	650	V
I_F, T_C≤150℃	4*	A
Q_C	11*	nC

* : per Leg



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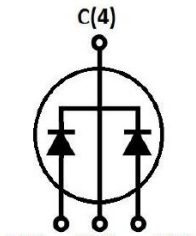


Benefits

- Unipolar device
- Greatly reduce switching losses
- No thermal crash in parallel devices
- Reduce system dependence on heat sinks

Applications

- Switch Mode Power Supply (SMPS), Power Factor Correction (PFC)
- Motor drive, photovoltaic inverter, uninterruptible power supply, Wind turbines, train traction systems, electric vehicles.

Halogen-Free

RoHS

Absolute Maximum Ratings T_C = 25℃ unless otherwise specified

Symbol	Parameter	Test Condition	Value	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		650	V
V_{RSM}	Surge Peak Reverse Voltage		650	V
V_{DC}	DC Blocking Voltage		650	V
I_F	Continuous Forward Current	T_C=25℃	11*	A
		T_C=135℃	5*	A
		T_C=150℃	4*	A
I_{FRM}	Repetitive Peak Forward Surge Current	T_C=25℃, tp=10ms, Half Sine Wave, D=0.3	15*	A
I_{FSM}	Non-repetitive Peak Forward Surge Current	T_C=25℃, tp=10ms, Half Sine Wave	35*	A
P_{TOT}	Power Dissipation	T_C=25℃	53.2*	W
		T_C=110℃	23*	
T_j	Operating Junction		-55 to 175	℃
T_{stg}	Storage Temperature		-55 to 175	℃

Thermal Characteristics

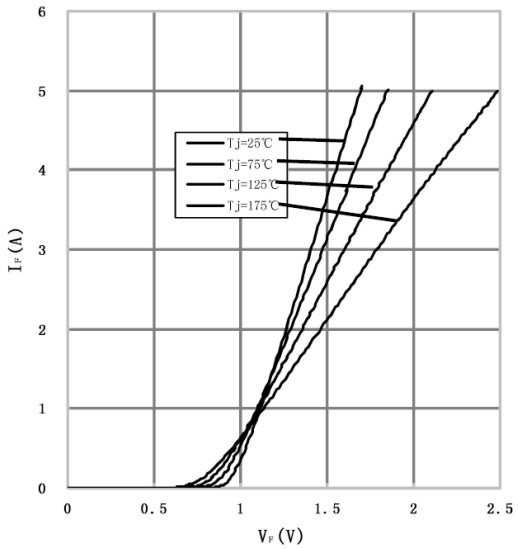
Symbol	Parameter	Test Condition	Value	Unit
			Typ.	
R_{thJc}	Thermal resistance from junction to case		2.82* 1.41**	℃/W

Electrical Characteristics, Nomination temperature Tj=25°C

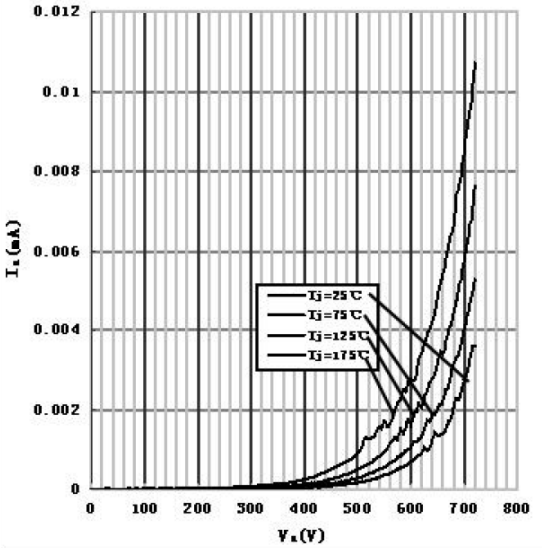
Symbol	Parameter	Test Condition	Numerical		Unit
			Typ.	Max.	
V_F	Forward Voltage	I_F=4A, T_j=25℃	1.57	1.7	V
		I_F=4A, T_j=175℃	1.8	2.5	
I_R	Reverse Current	V_R=650V, T_j=25℃	10	50	μA
		V_R=650V, T_j=175℃	20	100	
Q_C	Total capacitive Charge	V_R=400V,, T_j=150℃ $Qc = \int_0^{VR} C(V)dV$	11	-	nC
C	Total Capacitance	V_R=0V, T_j=25℃, f=1MHZ	181	220	pF
		V_R=200V, T_j=25℃, f=1MHZ	22.5	25	
		V_R=400V, T_j=25℃, f=1MHZ	20.5	21	

Performance Graphs

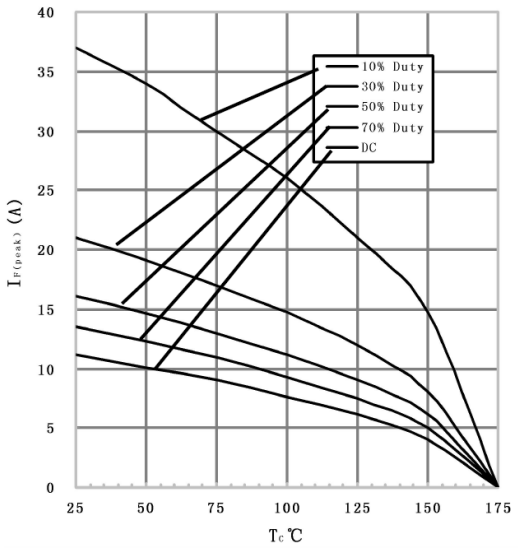
1)Forward IV characteristics as a function of T_j



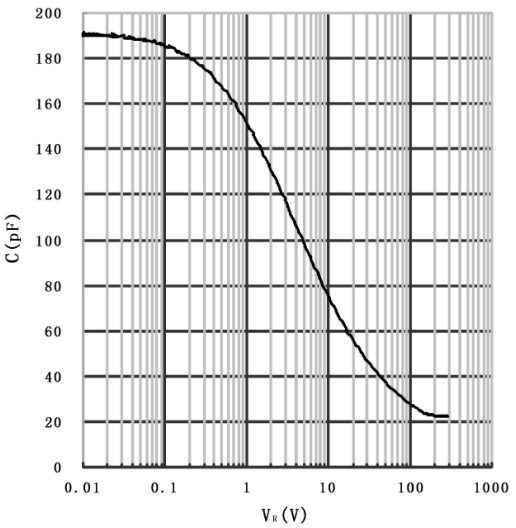
2)Reverse IV characteristics as a function of T_j



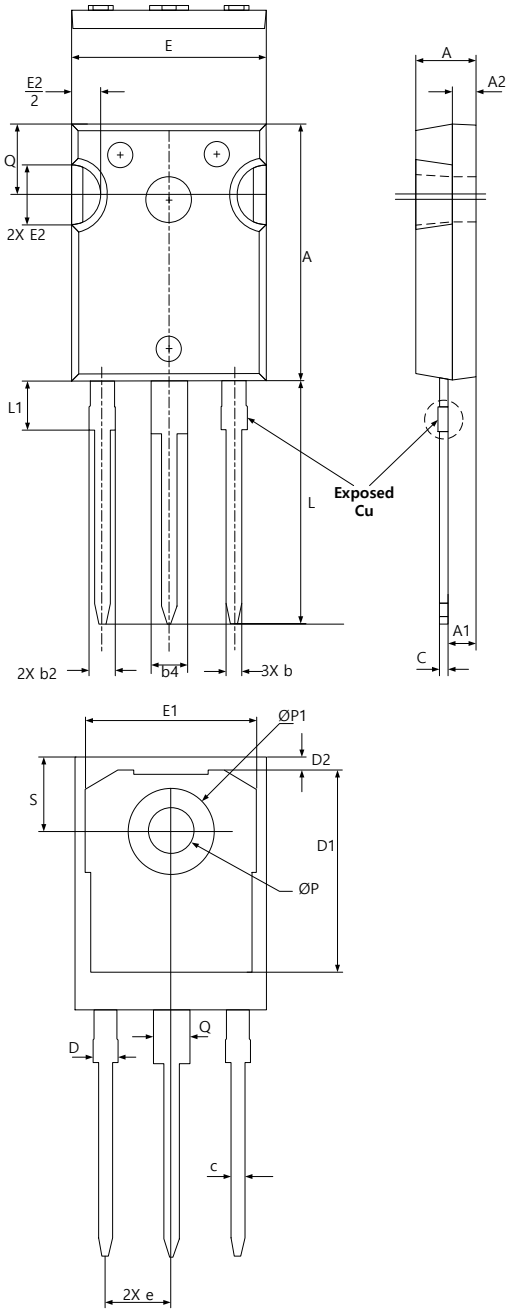
3)Current Derating



4)Capacitance VS. reverse voltage



Package Outline



SYMBOL	DIMENSIONS			NOTES
	MIN	NOM	MAX	
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
b	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.39	6
b3	1.91	2.00	2.34	
b4	2.87	3.00	3.22	6, 8
b5	2.87	3.00	3.18	
c	0.55	0.60	0.69	6
c1	0.55	6.00	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
e	5.44 BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ϕP	3.56	3.61	3.65	7
ϕP1	7.19 REF			
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	

Symbol	Parameter	Test Condition	Numerical		Unit
			Typ.	Max.	
M_d	Mounting torque	M3 Screw 6-32 Screw	1/8.8	-	Nm/ lbf.in.